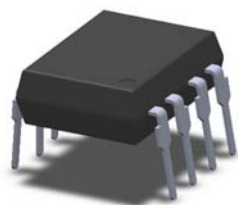
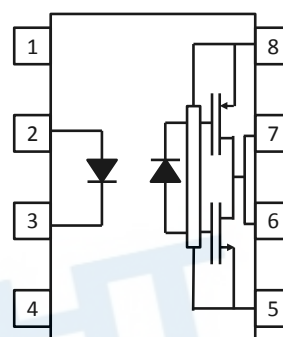


8PIN WIDE BODY IGBT/MOSFET 2.5A Output Current GATE DRIVER PHOTOCOUPLER ELW3120(D) Series



Schematic



Features:

- Peak Output Current : $I_{OP} = 2.5A$ (max)
- Threshold Input Current: $I_{FLH} = 5\text{ mA}$ (max)
- High isolation voltage between input and output (Viso=5000 V rms)
- Pb free and RoHS compliant.
- UL and cUL approved
- VDE approved
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Pin Configuration

- 1, No Connection
- 2, Anode
- 3, Cathode
- 4, No Connection
- 5, V_{EE}
- 6, V_{OUT}
- 7, V_{OUT}
- 8, V_{CC}

A 0.1 μ F bypass capacitor must be connected between pins 8 and 5

Description

The ELW3120 consists of an infrared light emitting diodes and integrated high gain, high-speed photo detectors. The device is housed in a 8 pin Wire body package.

The photo detector has an internal shield that provides a guaranteed common-mode transient immunity of $\pm 20\text{ kV}/\mu\text{s}$. It is suitable for direct gate driving circuit for IGBTs or power MOSFETs.

Applications

- Isolated IGBT/Power MOSFET Gate Drive
- Uninterruptible power supply
- Inverters
- Home appliances, such as fan heaters, etc.

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	25	mA
	Pulse Forward Current* ¹	I _{FP}	1	A
	Reverse voltage	V _R	5	V
Output	“H” Peak Output current	I _{OPH}	2.5	A
	“L” Peak Output Current	I _{OPL}	2.5	A
	Pear Output Voltage	V _O	30	V
	Supply Voltage	V _{CC}	30	V
	Isolation voltage * ²	V _{ISO}	5000	V rms
	Total Power Dissipation	P _T	300	mW
	Operating temperature	T _{OPR}	-40 ~ +100	°C
	Storage temperature	T _{STG}	-55 ~ +125	°C
	Soldering temperature * ³	T _{SOL}	260	°C

Notes:

*1 Pulse width ≤ 1μs, 300pps.

*2 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 to 4 are shorted together, and pins 5 to 8 are shorted together.

*3 For 10 seconds.

Electro-Optical Characteristics

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage	V_F	-	-	1.8	V	$I_F = 10\text{mA}$
Reverse Voltage	V_R	5	-	-	V	$I_R = 10\mu\text{A}$

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
High level supply current	I_{CCH}	-	1.8	3.2	mA	$I_F=10\text{mA}$, $V_{CC}=30\text{V}$ $V_O = \text{Open}$
Low level supply current	I_{CCL}	-	2.2	3.2		$I_F=0\text{mA}$, $V_{CC}=30\text{V}$ $V_O = \text{Open}$

Transfer Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
High Level Output Current*4	I_{OH}	-	-	-1	A	$I_F=10\text{mA}$, $V_{CC}=30\text{V}$, $V_O=V_{CC}-3\text{V}$
		-	-	-2.5		$I_F=10\text{mA}$, $V_{CC}=30\text{V}$, $V_O=V_{CC}-6\text{V}$
Low Level Output Current*4	I_{OL}	1	-	-		$I_F=0\text{mA}$, $V_{CC}=30\text{V}$, $V_O=V_{EE}+3\text{V}$
		2.5	-	-		$I_F=0\text{mA}$, $V_{CC}=30\text{V}$, $V_O=V_{EE}+6\text{V}$
High Level Output Voltage	V_{OH}	$V_{CC}-0.5$	-	-	V	$I_F=10\text{mA}$, $V_{CC}=30\text{V}$, $I_O=-100\text{mA}$
Low Level Output Voltage	V_{OL}	-	-	$V_{EE}+0.5$	V	$I_F=0\text{mA}$, $V_{CC}=30\text{V}$, $I_O=100\text{mA}$
Input Threshold Current	I_{FLH}	-	-	5	mA	$V_{CC}=30\text{V}$, $V_O > 5\text{V}$
Input Threshold Voltage	V_{FHL}	0.8	-	-	V	$V_{CC}=30\text{V}$, $V_O < 5\text{V}$
Under Voltage Lockout Threshold	V_{UVLO+}	11.0	-	13.5	V	$I_F=10\text{mA}$, $V_O > 5\text{V}$
Under Voltage Lockout Threshold	V_{UVLO-}	9.5	-	12.5	V	$I_F=10\text{mA}$, $V_O < 5\text{V}$

Switching Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Propagation delay time to output High level	t_{PLH}	50	-	400	ns	$I_F = 10mA$ $V_{CC} = 30V$ $C_g = 10nF, R_g = 10\Omega,$ $f = 10kHz, T_A = 25^\circ C$ Duty Cycle=50%,
Propagation delay time to output Low level	t_{PHL}	50	-	400	ns	
Pulse width distortion	$ t_{PHL} - t_{PLH} $	-	-	150	ns	
Propagation Delay Skew*5	t_{PSK}	-	-	150	ns	
Output rise time	t_R	-	80	-	ns	
Output fall time	t_F	-	80	-	ns	
Common Mode Transient Immunity at Logic High*6	CM_H	20	-	-	kV/ μS	$I_F = 10mA, V_{CC} = 30V,$ $T_A = 25^\circ C, V_{CM} = 1500V$
Common Mode Transient Immunity at Logic Low*7	CM_L	20	-	-	kV/ μS	$I_F = 0mA, V_{CC} = 30V,$ $T_A = 25^\circ C, V_{CM} = 1500V$

Notes:

*4 Max. pulse width=10 μS , max. duty cycle =1%

*5 Propagation delay skew is defined as the difference between the largest and smallest propagation delay times (i.e. t_{PHL} or t_{PLH}) of multiple samples. Evaluations of these samples are conducted under identical test conditions (supply voltage, input current, temperature, etc).

*6 Common mode transient immunity at output high is the maximum tolerable negative dv/dt on the trailing edge of the common mode impulse signal, V_{CM} , to assure that the output will remain high (i.e. $V_O > 15.0V$)

*7 Common mode transient immunity at output low is the maximum tolerable positive dv/dt on the leading edge of the common mode pulse signal, V_{CM} , to assure that the output will remain low (i.e. $V_O < 1.0V$)

Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

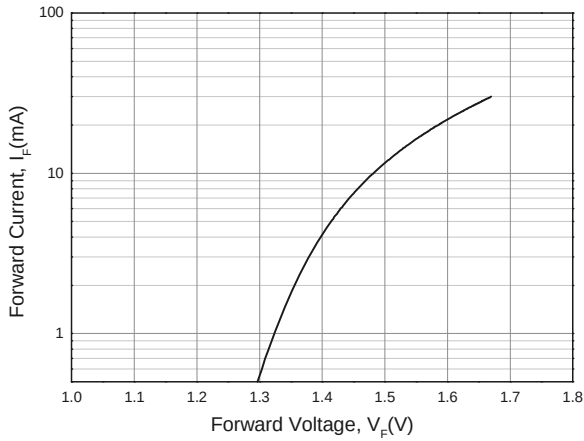


Figure 2. Threshold Input Current vs Ambient temperature

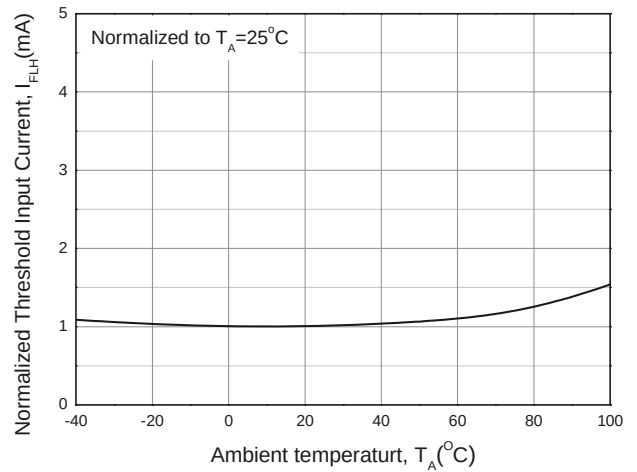


Figure 3. Low-level Supply Current vs Ambient temperature

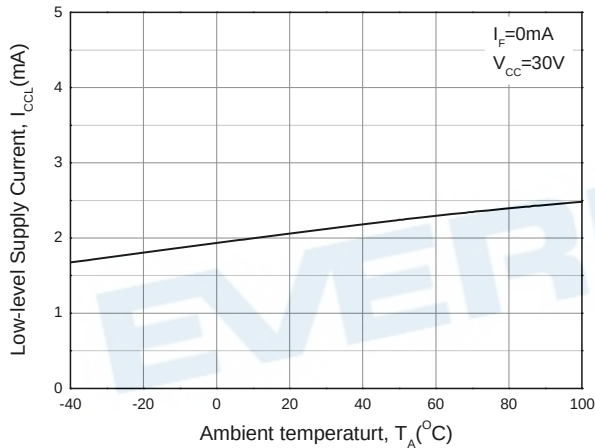


Figure 4. High-level Supply Current vs Ambient temperature

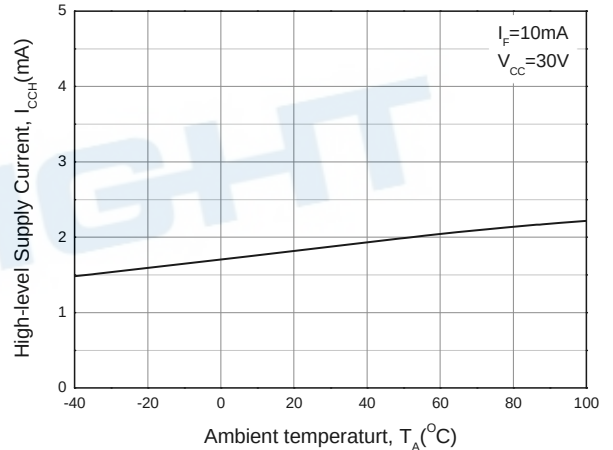


Figure 5. Low-level Output Voltage vs Ambient temperature

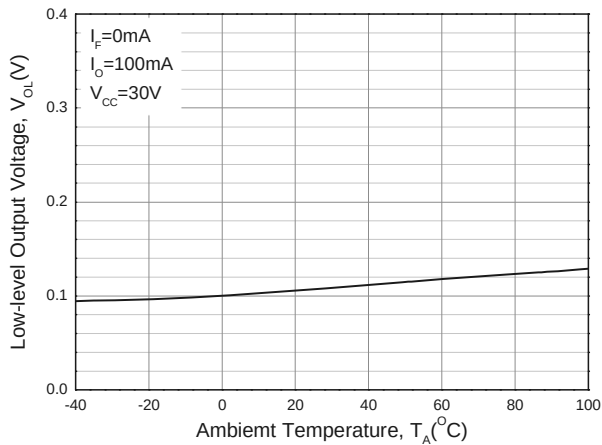


Figure 6. High-level Output Voltage vs Ambient temperature

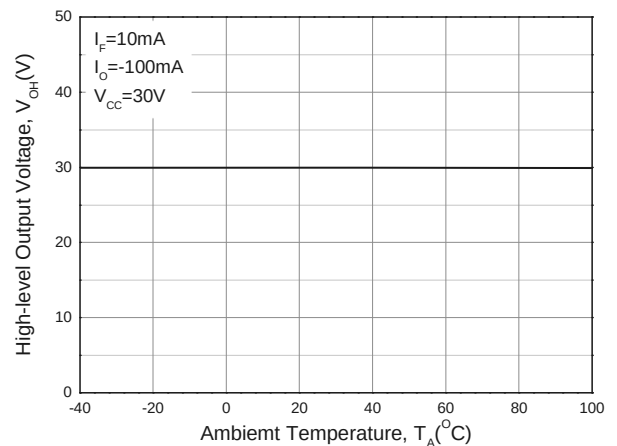


Figure 7. Low-level Output Voltage vs Peak low-level Output Current

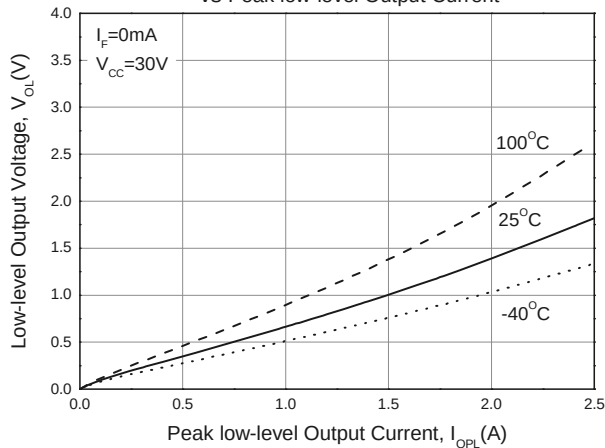


Figure 8. High-level Output Voltage Drop vs Peak low-level Output Current

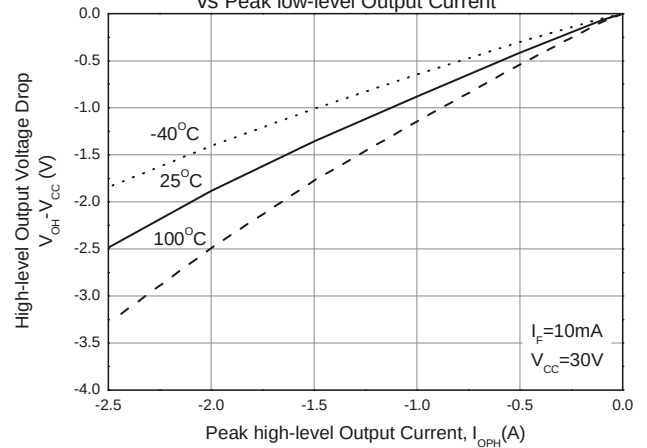


Figure 9. Propagation Delay Time vs Input Forward Current

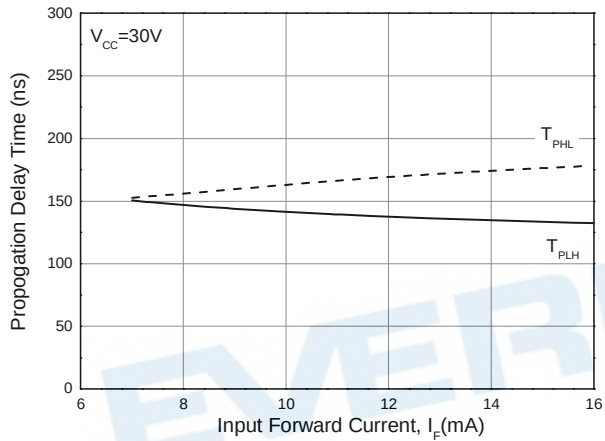


Figure 10. Propagation Delay Time vs Supply Voltage

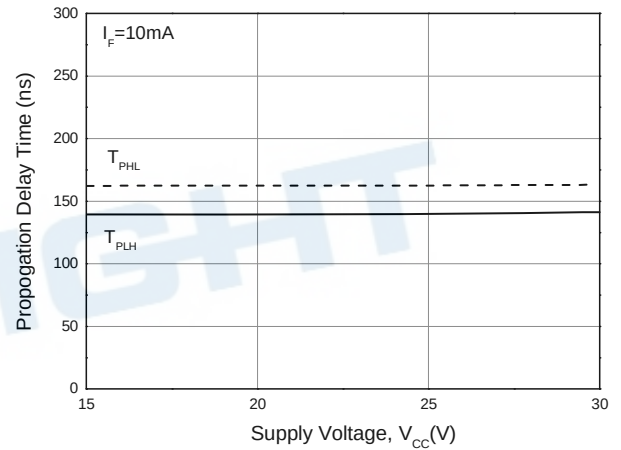


Figure 11. Propagation Delay Time vs Ambient Temperature

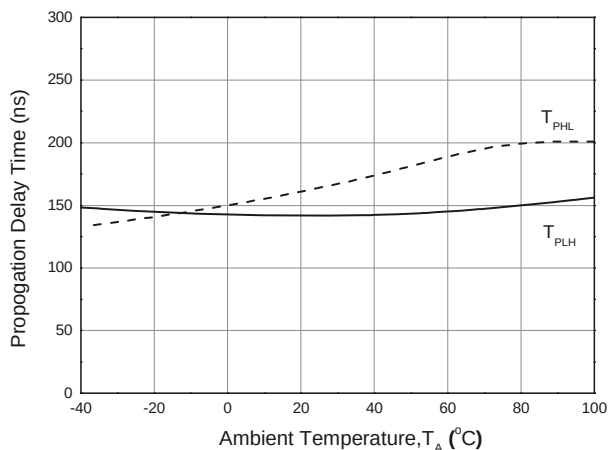


Fig. 12 I_{OH} Test circuit

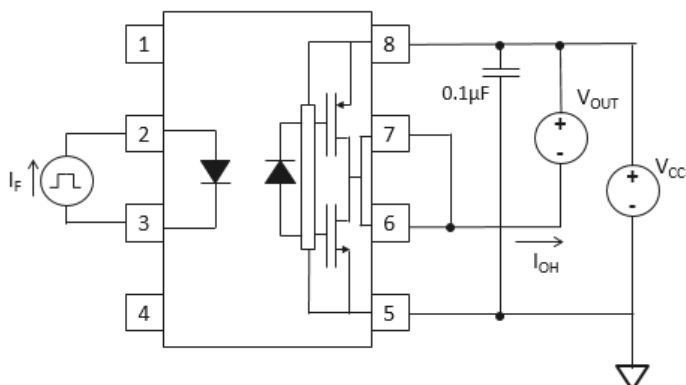


Fig. 13 I_{OL} Test circuit

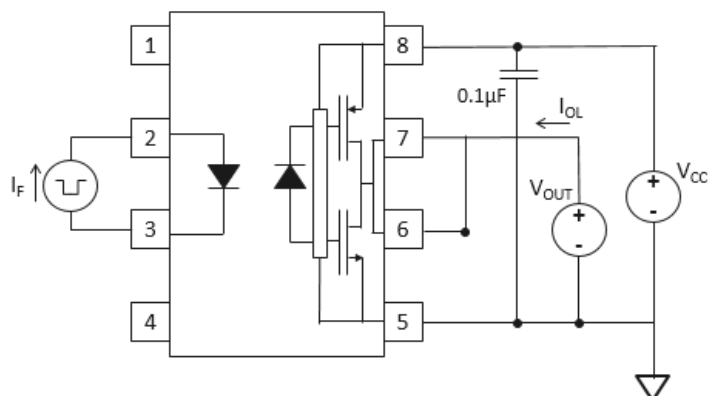


Fig. 14 V_{OH} Test circuit

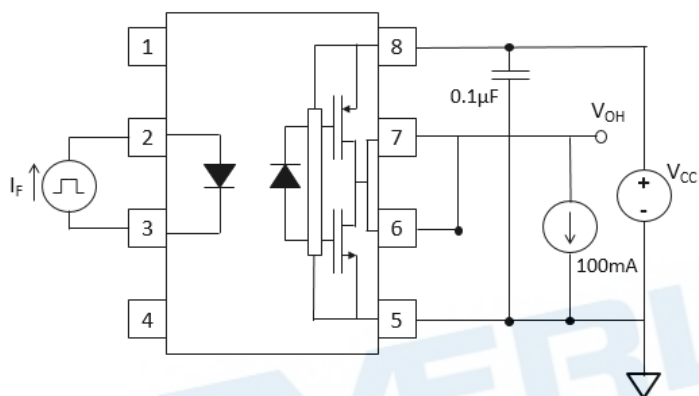


Fig. 15 V_{OL} Test circuit

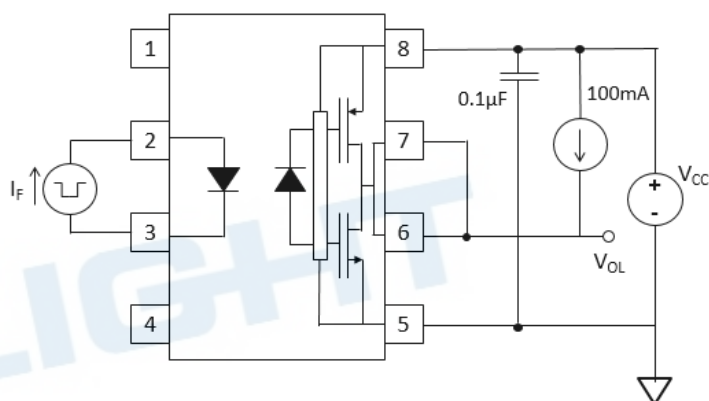


Fig. 16 I_{FHL} Test circuit

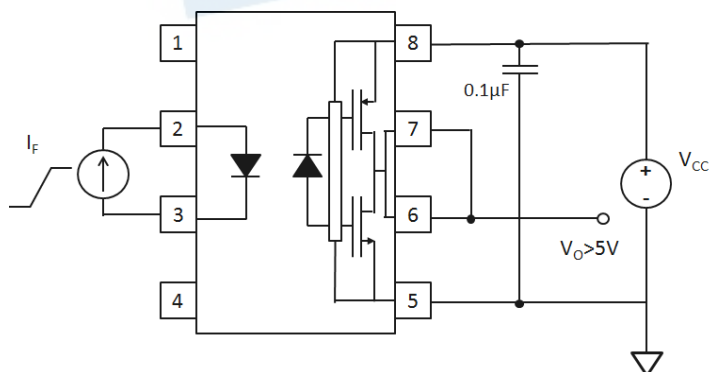


Fig. 17 UVLO Test circuit

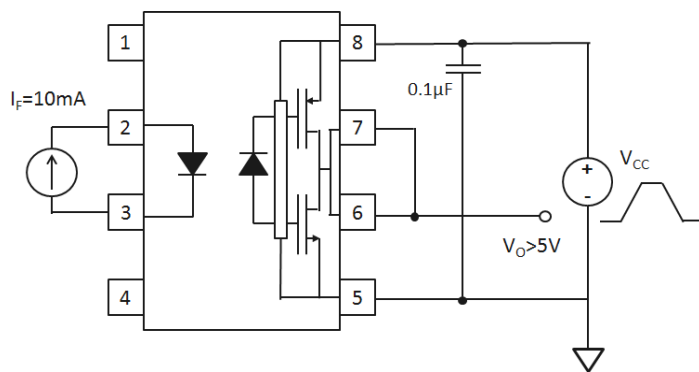


Fig. 18 Switching Time Test circuit

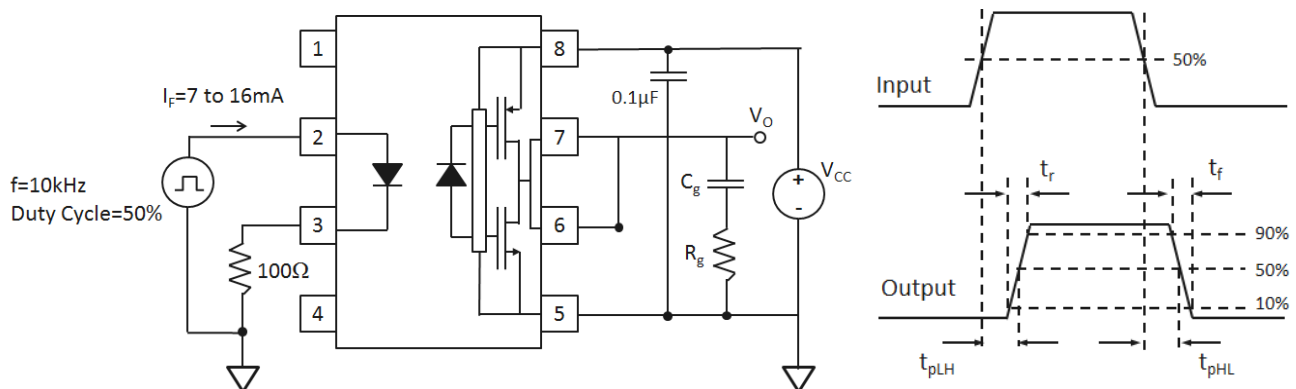
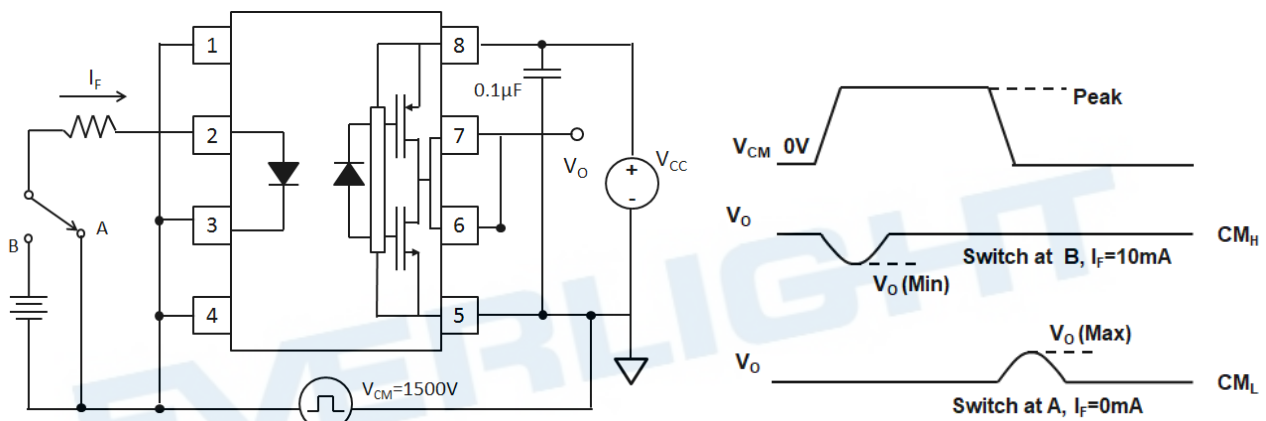


Fig. 19 CMR Test circuit



Order Information

Part Number

ELW3120X(Y)(D)-V

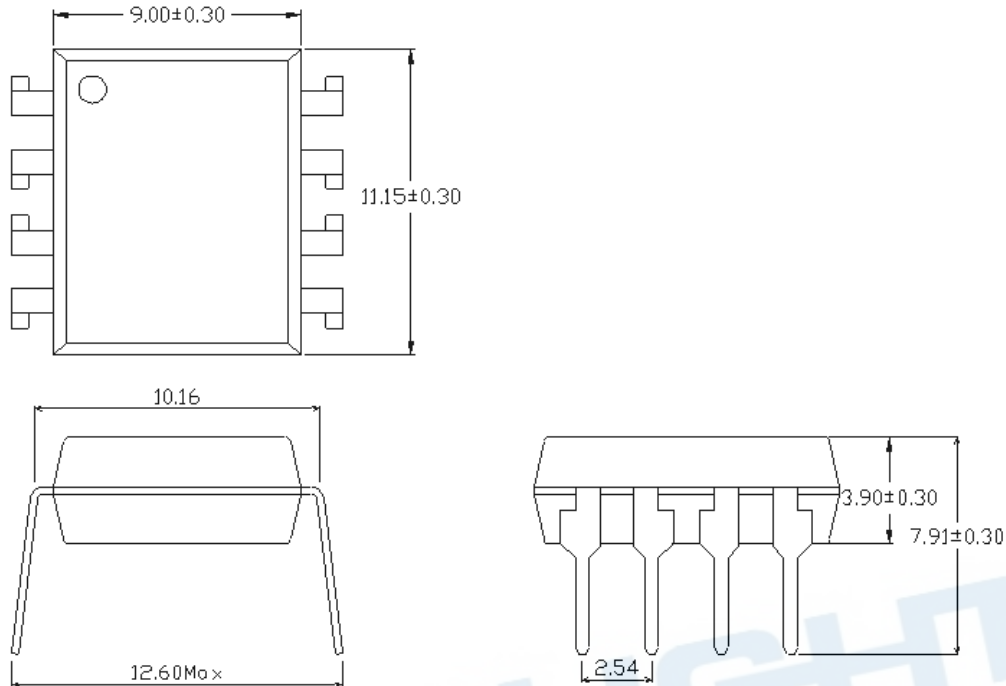
Note

EL = denotes EVERLIGHT
W3120 = part no.
X = Lead form option (S or none)
Y = Tape and reel option (TA, TB or none)
D = Customer Code
V = VDE safety (optional)

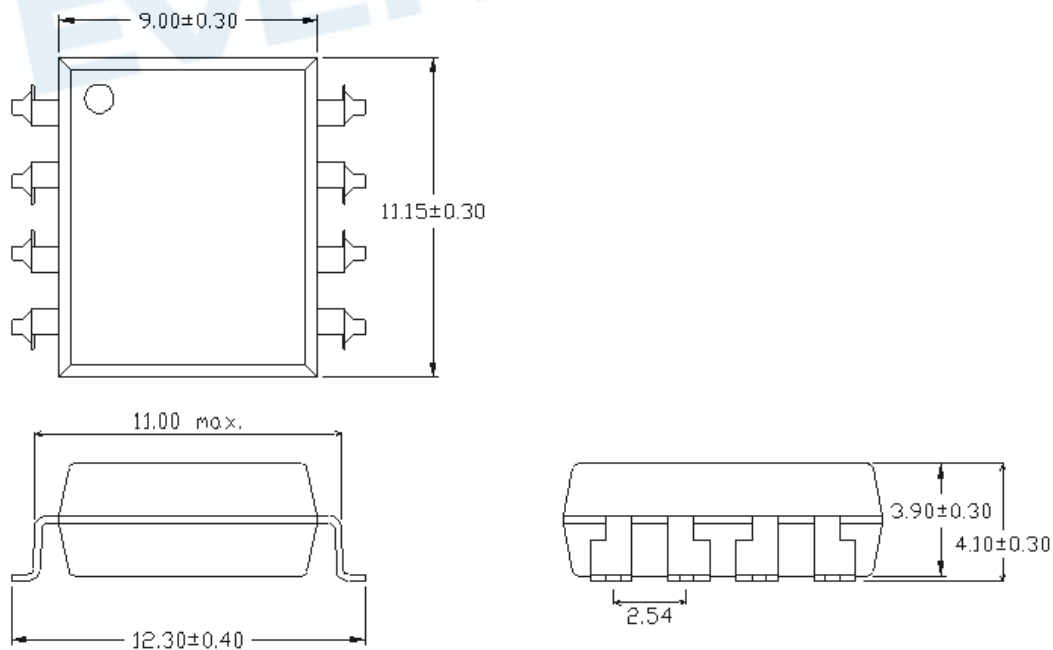
Option	Description	Packing quantity
None	Standard	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	500 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	500 units per reel

Package Dimension (Dimensions in mm)

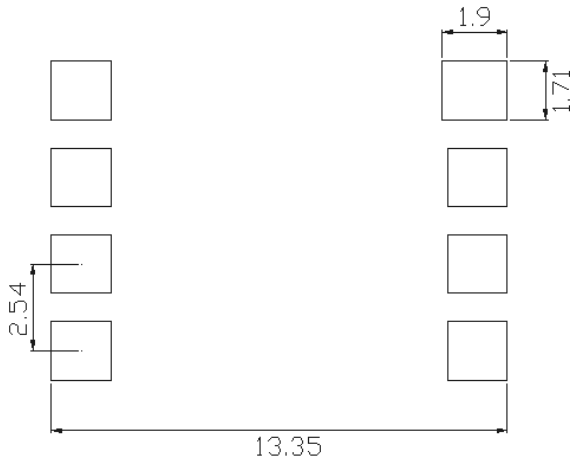
Standard DIP Type



Option S Type



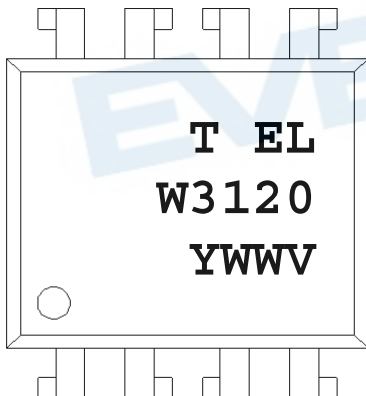
Recommended Pad Layout for Surface Mount Leadform



Notes.

Suggested pad dimension is just for reference only.
Please modify the pad dimension based on individual need.

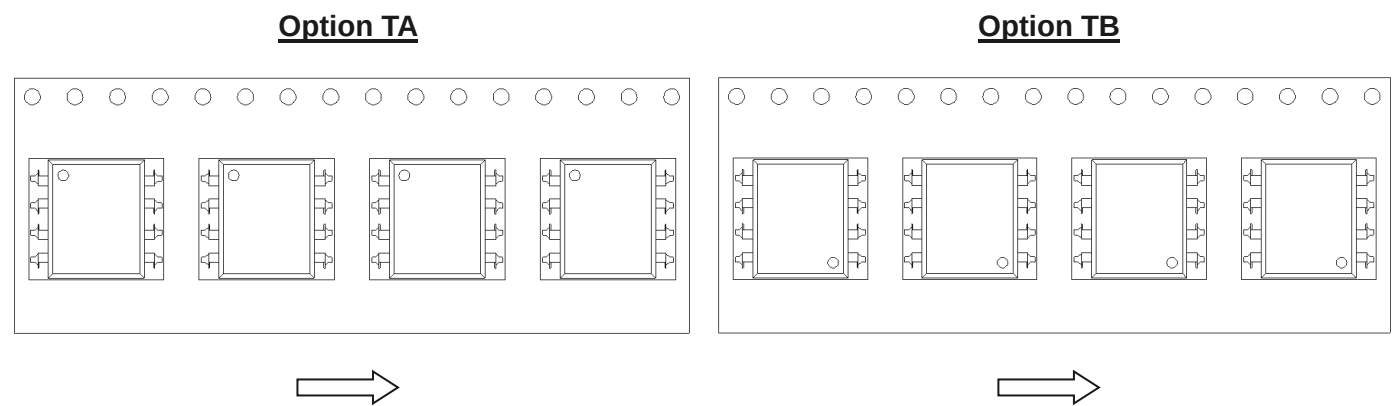
Device Marking



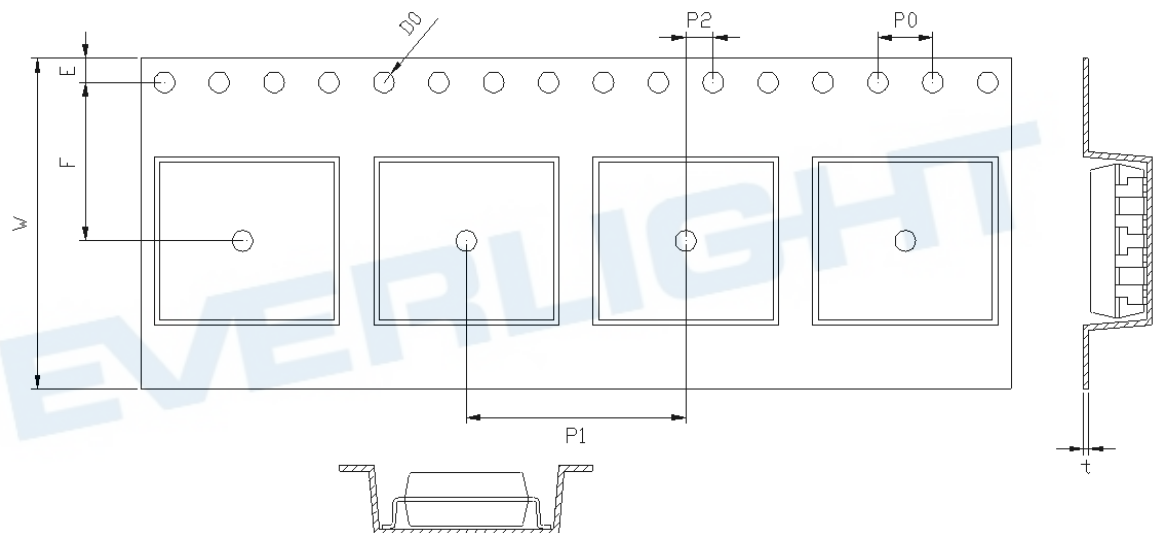
Notes

- T denotes Factory
No code : made in China
T : made in Taiwan
- EL denotes EVERLIGHT
- W3120 denotes Device Number
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- V denotes VDE (optional)

Tape & Reel Packing Specifications



Tape dimensions

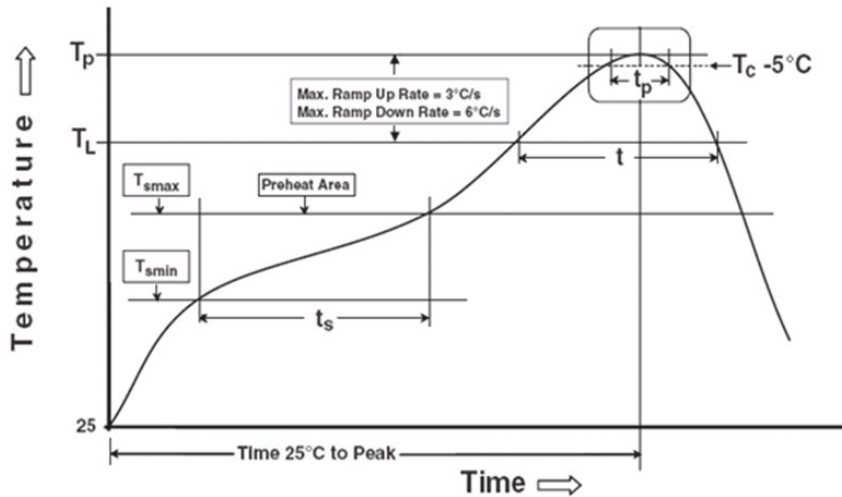


Dimension No.	W	E	F	Do
Dimension(mm)	24.00±0.3	1.75±0.1	11.5±0.1	1.5±0.1
Dimension No.	Po	P1	P2	t
Dimension(mm)	4.0±0.1	16.0±0.1	2.0±0.1	0.4±0.05

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max

Other

Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-100 sec
Peak Temperature (T_p)	260°C
Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	3 times

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